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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR



2SK3643

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3643 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

FEATURES

· Low on-state resistance

 $R_{DS(on)1} = 6 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = 10 \text{ V, I}_D = 32 \text{ A)}$

 $R_{DS(on)2} = 9 \text{ m}\Omega \text{ MAX.}$ (Vgs = 4.5 V, ID = 32 A)

• Low Ciss: Ciss = 2400 pF TYP.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vss = 0 V)	Voss	30	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±64	Α
Drain Current (pulse) Note1	D(pulse)	±256	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	40	W
Total Power Dissipation	P _{T2}	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C
Single Avalanche Current Note2	las	40	Α
Single Avalanche Energy Note2	Eas	160	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 15 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3643-ZK	TO-252 (MP-3ZK)

(TO-252)



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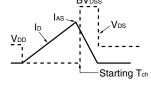
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 30 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5		2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 32 A	19	39		S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = 10 V, I _D = 32 A		4.7	6	mΩ
	RDS(on)2	V _{GS} = 4.5 V, I _D = 32 A		6.3	9	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		2400		pF
Output Capacitance	Coss	V _{GS} = 0 V		920		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		320		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 15 V, I _D = 32 A		14		ns
Rise Time	tr	V _{GS} = 10 V		14		ns
Turn-off Delay Time	t _{d(off)}	$R_G = 10 \Omega$		75		ns
Fall Time	t _f			23		ns
Total Gate Charge	QG	V _{DD} = 24 V		48		nC
Gate to Source Charge	Qgs	V _{GS} = 10 V		8.4		nC
Gate to Drain Charge	Q _{GD}	I _D = 64 A		12		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 64 A, V _{GS} = 0 V		0.96		V
Reverse Recovery Time	trr	IF = 64 A, VGS = 0 V		45		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		44		nC

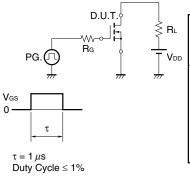
Note Pulsed: PW \leq 350 μ s, Duty Cycle \leq 2%

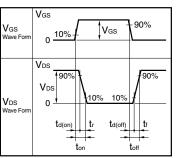
TEST CIRCUIT 1 AVALANCHE CAPABILITY

$V_{GS} = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc \downarrow 50 \Omega$ BV_{DSS} $As \Rightarrow \downarrow 1$



TEST CIRCUIT 2 SWITCHING TIME



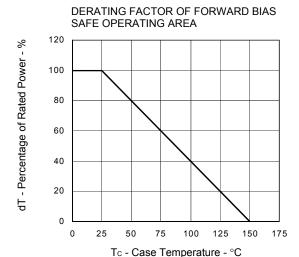


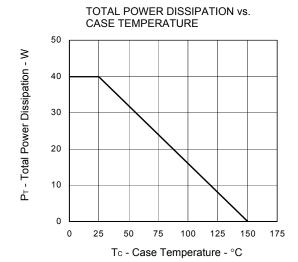
TEST CIRCUIT 3 GATE CHARGE



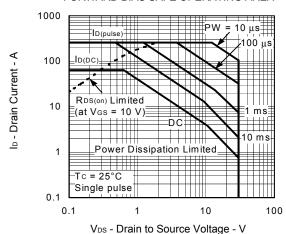


TYPICAL CHARACTERISTICS (TA = 25°C)

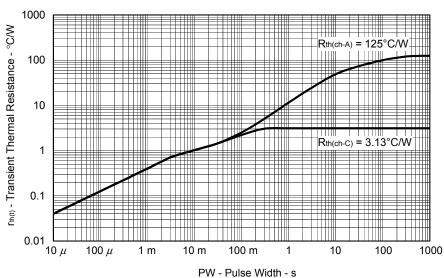




FORWARD BIAS SAFE OPERATING AREA

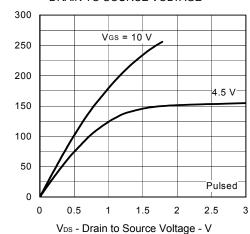


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

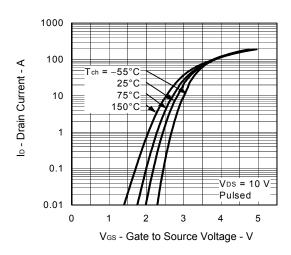


lo - Drain Current - A

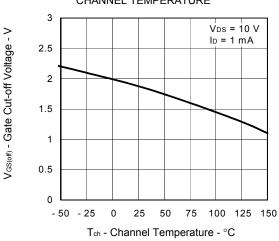
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



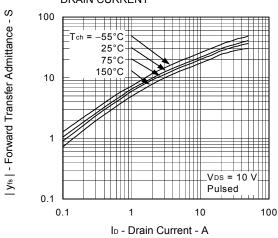
FORWARD TRANSFER CHARACTERISTICS



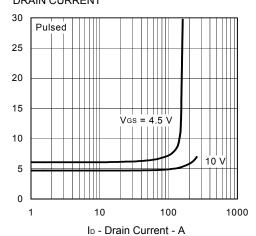
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



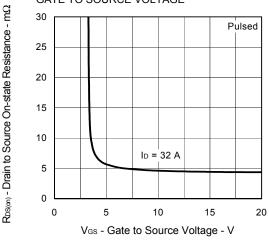
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



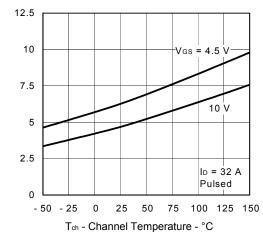
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



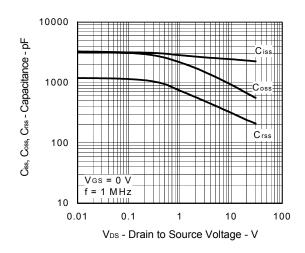
R_{DS(m)} - Drain to Source On-state Resistance - mΩ

RDS(on) - Drain to Source On-state Resistance - m\Omega

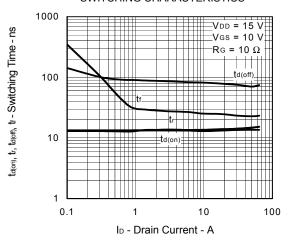
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



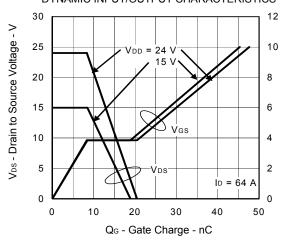
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



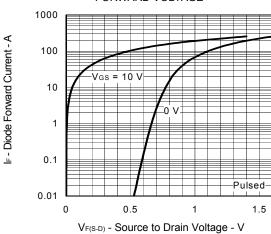
SWITCHING CHARACTERISTICS



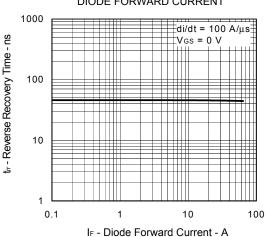
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

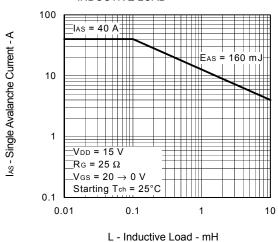


REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

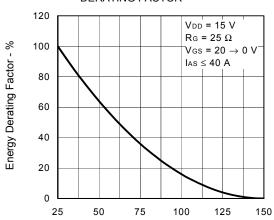


Ves - Gate to Source Voltage - V

SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



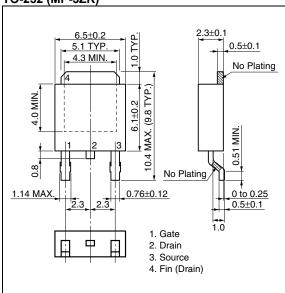
SINGLE AVALANCHE ENERGY DERATING FACTOR



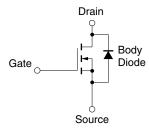
Starting Tch - Starting Channel Temperature - °C

★ PACKAGE DRAWING (Unit: mm)





EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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